組立後の洗浄工程削減へ!

Eliminate cleaning process after assembly!

フラックス残渣レスペースト

Less flux residue paste

NP303-FLV-T4

フラックス残渣が残らず洗浄不要!

Since flux residue does not remain, cleaning is unnecessary!

Niなどのヌレにくい母材に対してもヌレ性良好!

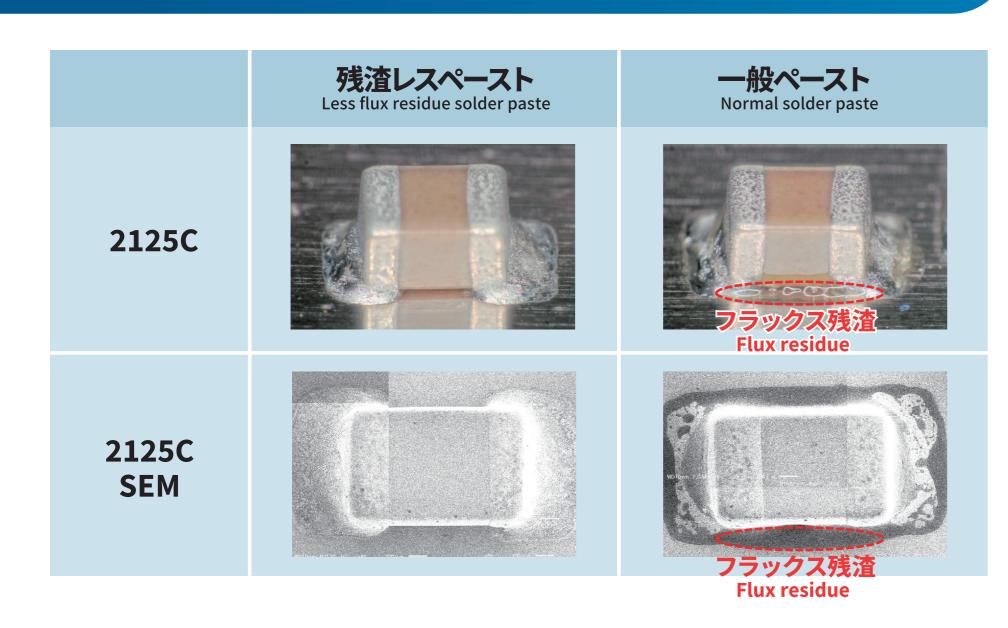
Wettability to the parts that are hard to be wet like Ni are also good!

N2+真空リフロー対応でボイド発生を抑制!

Suppress occurrence of void by N2 + vacuum reflow furnace!

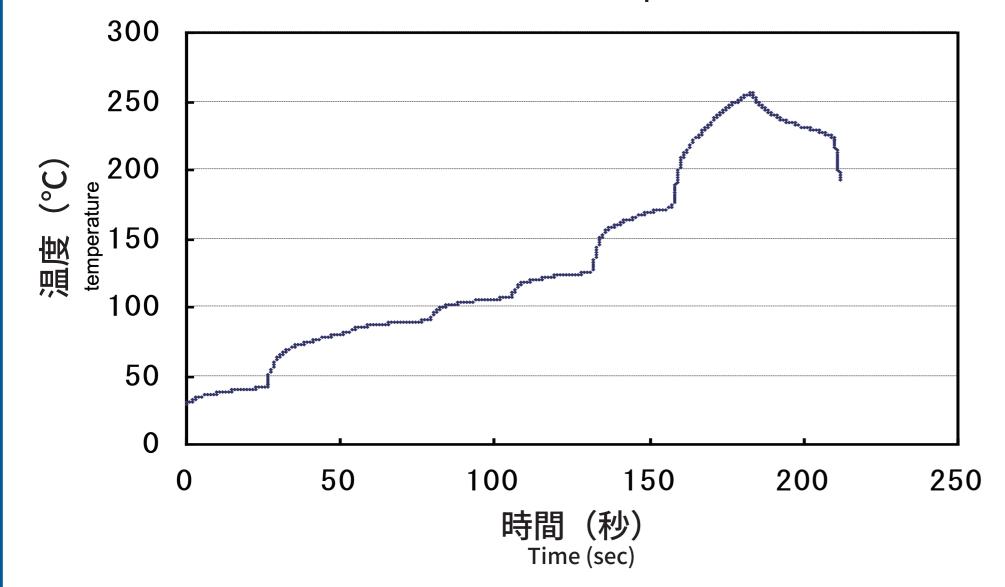
揮発によるフラックス残渣抑制

Suppression of flux residue by volatilization



推奨リフロープロファイル

Recommended reflow profile



	試験条件 Test condition	推奨条件 Recommended conditions
昇温速度 Temperature increase rate	1.0sec.	2sec.以下
プリヒート(100°C-170°C) Preheat	60.8sec.	40-70sec.
昇温速度(170°C-220°C) Temperature increase rate	4.6°C/sec.	4°C/sec.以上
>220°C	46sec.	30-90sec.
ピーク温度 Peak temperature	260.6°C	250-270°C
酸素濃度 Oxygen concentration	500ppm	500ppm以下
真 空到達度 Degree of vacuum	3.9kPa	10kPa以下

ギ酸リフロー対応 フラックス残渣レスペースト

Less flux residue paste applied for formic acid reflow

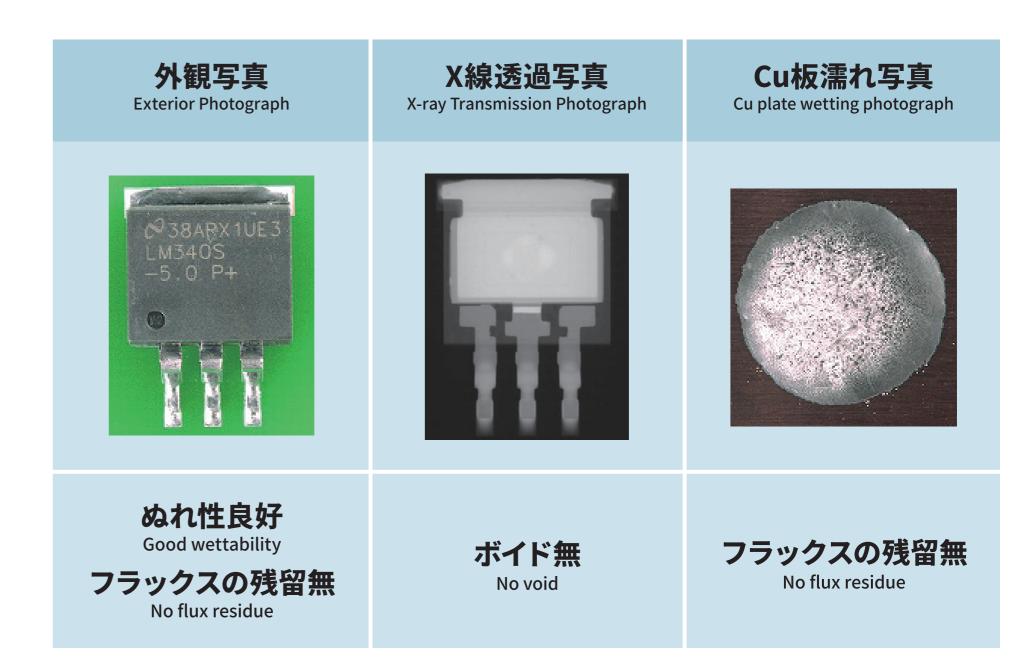
NP303-FL001-T4

ギ酸リフローによりフラックス残渣、ボイドゼロ!

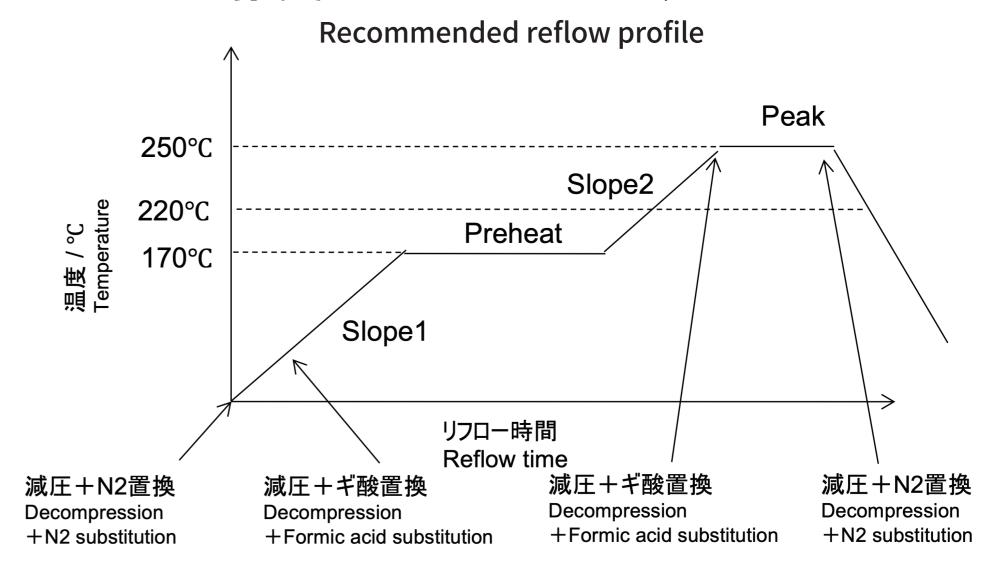
No flux residue and void due to formic acid reflow!

ギ酸リフロー性の検証結果

Test result of reflowability for Formic acid reflow



推奨リフロープロファイル



Step	条件 Conditions	
Slope1, 2	2.0°C/sec以内 within 2.0°C/sec	
Preheat	170°C、60sec以上 more than 170°C60sec	
Peak	Sn3Ag0.5Cuの融点 (217°C)+15°C以上 melting point of Sn3Ag0.5Cu+more than 15°C	
220°C以上 (半田の融 点以上) More than 220°C(more than melting point of solder)	30sec以上 more than 30sec	
ギ酸導入のタイミング Supply timing of formic acid	Preheat前とPeak温度前に2回 Total of 2 times before preheat and peak temperature	

